TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

# T A 1 3 7 2 F N G

#### VHF Band RF Modulator IC for VCRs and Set top boxes

The TA1372FNG is a VHF band RF modulator IC that features PLL-based RF carrier and sound intercarrier oscillation.

There is no external parts of RF Oscillator and Sound Oscillator. Therefore, PCB design and adjustment with much time are not required.

The TA1372FNG is compatible with CH 3 & CH 4 (U.S.A. channel) of NTSC television system.

SSOP16-P-225-0.65B

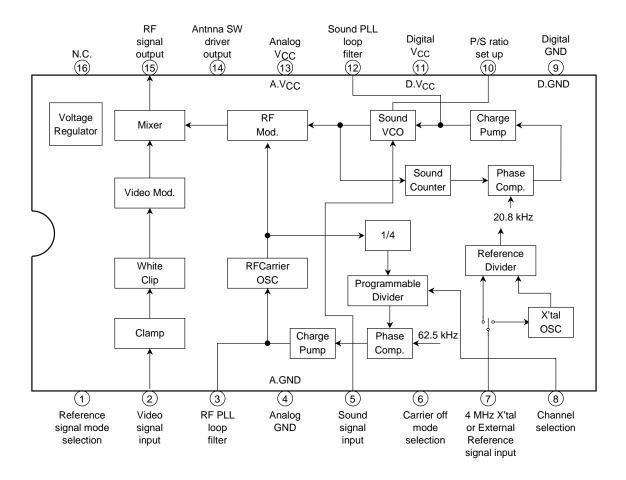
Weight: 0.07 g (typ.)

#### Features

- RF Oscillator is all built in IC and external tank circuit is not required. (U.S.A. channels CH 3 & CH 4)
- Sound Oscillator is all built in IC and external tank circuit is not required. Formats supported: System M
- The Picture to Sound ratio is set up by external resistance.
- Muted RF output on power-on and as required.
- Reference signal can use 4MHz and 3.579545MHz. These modes are selected by pin 1.
- In Carrier off mode, Supply current is saved by stopping Sound VCO.
- There is White Clip Through Mode in test mode.
- Package is improved to Lead-Free

# <u>TOSHIBA</u>

#### **Block Diagram**



Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purpose.

## Pin Description ( $V_{CC} = 5.0 \text{ V}$ , Ta = 25°C)

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purpose.

Pin No.	Name	DC Voltage (typ.)	AC Voltage (typ.)	Interface equivalent circuit	Note
1	Reference signal Mode selection	H: 5 V M: 2.5V L: 0 V	_	D.V <sub>CC</sub>	Reference signal Mode can be selected this pin. High or Open: 4MHz external input mode Middle: 3.579545MHz external input mode Low: Internal Oscillation Mode with 4MHz X'tal
2	Video signal Input	2.4 V (sync tip)	500 mV <sub>p-p</sub> (80% modulation)	2 A.V <sub>CC</sub>	Sync tip clamp input. It is used by AC coupling. Video modulation depth is set by level of input signal on this pin. White clip level for IC is set internally for DC, but it will change by the high frequency-factor.
3	RF PLL loop filter			3 C 2 KΩ C 2 KΩ C 2 KΩ D.V <sub>CC</sub> D.V <sub>CC</sub> D.V <sub>CC</sub>	RF oscillation frequency is compared with RF setting frequency(pin 8), and the error is outputted by Charge pump. LPF for high frequency rejection is connected to this terminal. And the voltage for RF VCO control is generated. The reference frequency is 62.5 kHz.
4	Analog GND	(0 V)			Analog GND
5	Sound signal input	H: 5 V M: 2.5V L: 0 V (normal mode)	167 mV <sub>p-p</sub> (100% FM modulation)	5	Sound modulation depth is set by level of sound signal input on this pin. Sound pre-emphasis is applied before this pin. This pin is also used for switching test mode. Normally this pin is used at 0 V DC (used by AC coupling). H: Test mode M: Test mode (White Clip through mode) L (open): Normal mode

Pin No.	Name	DC Voltage (typ.)	AC Voltage (typ.)	Interface equivalent circuit	Note
6	Carrier off mode selection	H: 5 V L: 0 V		6 Cy μ Cy μ Cy μ Cy μ Cy μ D.V <sub>CC</sub> D.V <sub>CC</sub>	This terminal is selection of Carrier off-mode and Antenna SW driver output. High : Carrier ON Antenna SW High Low or Open : Carrier OFF Antenna SW Low
7	4 MHz X'tal	4.3 V (External input mode) 2.7 V (Internal oscillation mode)		D.V <sub>CC</sub> 3.6 V (Note2) 0.1 mA Note1: Internal oscillation mode OFF Note2: External input mode OFF	As reference signal, either 4-MHz crystal resonator can be connected to this pin for internal oscillation or external signal can be input. Reference signal Mode can be selected pin 1.
8	Channel select	H: 5 V L: 0 V	_	Cy 021 10 kΩ D.V <sub>CC</sub> D.V <sub>CC</sub> D.V <sub>CC</sub>	This terminal is the selection of RF VCO oscillation frequency. Open or High : USA 3ch Low : USA 4ch
9	Digital GND	(0 V)	_	_	Digital GND
10	P/S ratio set up	5V (Pin Open)	_	A.V <sub>CC</sub> A.V <sub>CC</sub> A.V <sub>CC</sub> A.V <sub>CC</sub>	P / S ratio is set up by connecting resistance with this terminal between GND.
11	Digital Vcc	(5 V)			Digital Vcc

Pin No.	Name	DC Voltage (typ.)	AC Voltage (typ.)	Interface equivalent circuit	Note
				D.V <sub>CC</sub>	Sound VCO oscillation frequency is compared with 4.5MHz, and the error is outputted by Charge pump.
12	Sound PLL loop filter	_	_		LPF for high frequency rejection is connected to this terminal. And the voltage for sound VCO control is generated.
				D.GND	The reference frequency is 20.8 kHz.
13	Analog Vcc	(5 V)	_		Analog Vcc
14	Antenna SW driver output	H: 4.1 V L: 0 V		A.Vcc	This terminal is a driver output for an Antenna SW switching and controlled by the terminal 6. The maximum output current is 15mA.
15	RF signal output	3.2 V	93dBµV	A.V <sub>CC</sub>	RF signal output pin. Low-impedance emitter-follower output
16	N.C.			<u> </u>	

#### Explanation in each mode

#### 1. Reference signal Mode selection (Pin 1)

As reference signal, either 4-MHz crystal resonator can be connected to this pin for internal oscillation or external signal can be input. Reference signal Mode can be selected pin 1. 4MHz and 3.579545MHz can be used for the frequency of an external input signal.

Voltage of pin 1	Reference signal mode			
High or Open	4MHz External input			
Middle	3.579545MHz External input			
Low	Internal oscillation with 4MHz X' tal			

#### 2. Test mode selection (Pin 5)

Pin 5 is also used for switching test mode. Normally this pin is used at 0 V DC (used by AC coupling). White clip mode is prepared into test mode. ( e.g. when modulation characteristics for near-100% modulation are being checked.)

Voltage of pin 5	Mode			
High	Test mode			
Middle	White Clip through mode			
Middle	(Test mode)			
Low or Open	Normal mode			

If the voltage of a terminal 5 becomes more than 1.2V, it will change to the test mode. Be careful of the influence of a noise etc.

#### 3. Carrier off mode selection (Pin 6)

Pin 6 is selection of Carrier off-mode and Antenna SW driver output. In Carrier off mode, Supply current is saved by stopping Sound VCO.

Voltage of pin 6	RF&sound oscillation	Antenna SW driver output (pin 14)
High	ON	High
Low or Open	OFF	Low

When changing a carrier ON, RF output is muted the time of about 130 msec. Mute of RF output is for avoiding the influence of the noise by RF carrier frequency being unstable. At the time of Channel switching, RF output is muted similarly.

#### 4. Channel selection (Pin 8)

Pin 8 is the selection of RF VCO oscillation frequency.

Voltage of pin 8	Channel				
High or Open	USA 3ch (61.25MHz)				
Low	USA 4ch (67.25MHz)				

#### 5. P/S ratio set up (Pin 16)

P / S ratio is set up by connecting resistance with pin 16 between GND. P / S ratio can be set as the range of -9dB to  $\cdot17dB.$ 

#### Maximum Ratings (Ta = 25°C)

The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, these operations with exceeded ratings may cause break down, damage and/or degradation to any other equipment.

Applications using the device should be designed such that each maximum rating will never be exceeded in any operating conditions. Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this documents.

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	6	V
Power dissipation (Note 1)	PD	810	mW
Input terminal voltage	V <sub>IN</sub>	$GND-0.3V_{CC}+0.3$	V
Operating temperature	T <sub>opr</sub>	-20~75	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C

Note 1: Power dissipation in the IC alone. If the device is operated at Ta  $> 25^{\circ}$ C, this parameter must be derated by 6.5 mW per 1°C.

# Electrical Characteristics (V<sub>CC</sub> = 5.0 V, Ta = 25°C, When there is no indication of conditions $f_p = 61.25$ MHz)

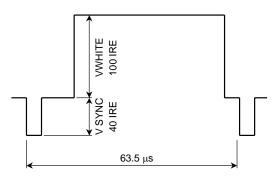
	No.	Characteristics	Symbol	Min	Тур.	Max	Unit	Note
	1-1	Supply voltage	Vcc	4.5	5.0	5.5	V	
	1-2	Operating frequency range	fop	61.25	-	67.25	MHz	fp frequency
Entire IC	1-3	Supply current 1 (Normal mode)	lcc1	38	45	51	mA	Normal moe,IANT SW=0mA
	1-4	Supply current 2 (Carrier off mode)	lcc2	2.5	3.5	4.5	mA	Carrier off mode
	2-1-1	Video RF output level	Vo	90	93	96	dB $\mu$ V	50- $\Omega$ termination, staircase (B/W) signal, 0.5-Vp-p input
	2-1-2	Video RF output level (Difference of channel)	ΔVo	-1.2	0.2	0.8	dB	50- $\Omega$ termination, staircase (B/W) signal, 0.5-Vp-p input, Vo(3ch) – Vo(4ch)
	2-2	Video modulation depth	mp	76	80	84	%	White signal:0.5Vp-p input
	2-3	White clipping level	mpMAX	88	92	96	%	White signal:1.0Vp-p input
	2-4	Differential gain	DG	-5	0	+5	%	10-step staircase signal: 0.5-Vp-p input (chroma signal = 20 IRE), 9th step
	2-5	Differential phase	DP	-5	0	+5	0	10-step staircase signal: 0.5-Vp-p input (chroma signal = 20 IRE), 9th step
	2-6	Video S/N ratio	mpS/N	50	51.5	-	dB	0.1 MHz~4.2 MHz, unweighted, 50% White signal input
	2-7	Video frequency responce	fv	-2.4	-0.4	1.6	dB	0.1 MHz~4.2 MHz, referenced to 1 MHz
Video	2-8	Average picture level drift	mp(APL)	-3	0	+3	%	10%~90% APL, referenced to 50%, variation in video modulation depth
Block	2-9	Sync crush level	∆sync	-	1	3	%	{1 - (Vsync/Vwhite) × (100/40)}
	2-10	Chroma beat	Vc	-	-75	-70	dB	3.58MHz sine wave: 0.5-Vp-p input, Referenced to video carrier level, P/S ratio = -16dB
	2-11-1	Video RF 2nd harmonic	V2fp	-	-35	-30	dB	Referenced to video carrier level
	2-11-2	Video RF 3rd harmonic	V3fp	-	-33	-28	dB	Referenced to video carrier level
	2-11-3	Video RF 4th harmonic	V4fp	-	-55	-50	dB	Referenced to video carrier level
	2-12	Video harmonic	Vph	-	-53	-50	dB	1MHz sine wave: 0.5-Vp-p input, Referenced to fp+1MHz level, Level of fp+2MHz
	2-13-1	Video carrier frequency accuracy 1	∆fp4	-50	0	50	kHz	Reference frequency 4MHz, Internal oscillation mode, Series capacitance of crystal : 6pF
	2-13-2	Video carrier frequency accuracy 2	∆fp358	-0.008	-	+34	kHz	Reference frequency 3.579545MHz, External signal input mode

	No.	Characteristics	Symbol	Min	Тур.	Max	Unit	Note
	3-1-1	Picture to Sound ratio	RP/S	-18	-16	-14	dB	P/S ratio: -16dB set-up, Connecting a 16k ohm resistor between pin 10 and GND. staircase (B/W) signal: 0.5-Vp-p input
	3-1-2	Picture to Sound ratio (Difference of channel)	∆RP/S	-0.5	0	0.5	dB	P/S ratio: –16dB set-up, Connecting a 16k ohm resistor between pin 10 and GND. staircase (B/W) signal: 0.5-Vp-p input, RP/S (3ch) –RP/S (4ch)
	3-2-1	Maximum P/S ratio	RP/S max	-11	-9	-	dB	P/S ratio: maximum set-up, Pin 10 is open. staircase (B/W) signal: 0.5-Vp-p input
·	3-2-2	Minimum P/S ratio	RP/S min	-	-18	-16	dB	P/S ratio: minimum set-up, Pin 10 is connected to GND. staircase (B/W) signal: 0.5-Vp-p input
	3-3	Sound modulation sensitivity	βFM	0.27	0.3	0.33	kHz/mV	1-kHz sine wave: 167 mVp-p input $\beta FM = \Delta f (kHz)/167 (mV)$
Sound Block	3-4-1	Sound S/N ratio 1	S/N(FM1)	51	52.5	-	dB	1-kHz sine wave input, $\pm 25 \text{ kHz Dev.} = 0 \text{dB}$ , Inter Carrier demod., De-Emph = IN
DIUCK	3-4-2	Sound S/N ratio 2 (with video signal)	S/N(FM2)	50	51.5	-	dB	1-kHz sine wave input, ±25 kHz Dev. = 0dB, Color bar signal: 0.5-Vp-p input, Inter Carrier demod., De-Emph = IN
	3-5	Sound distortion	THD	-	0.3	0.5	%	1-kHz sine wave: ±25kHz Dev.
	3-6	Sound frequency response	fs	-2	0	2	dB	100 Hz~100 kHz, 1-kHz reference
	3-7	Maximum FM deviation	ΔDev	400	450	-	%	1-kHz sine wave input, THD<3%
	3-8-1	Sound RF 2nd harmonic	VSH1	-	-70	-65	dB	P/S ratio = -16dB set-up, Video carrier level reference
	3-8-2	Sound RF 3rd harmonic	VSH2	-	-75	-70	dB	P/S ratio = -16dB set-up, Video carrier level reference
	3-9-1	Sound carrier frequency accuracy 1	∆fs4	-750	0	750	Hz	Reference frequency 4MHz, Internal oscillation mode, Series capacitance of crystal : 6 pF
	3-9-2	Sound carrier frequency accuracy 2	∆fs358	-0.6	-	-	Hz	Reference frequency 3.579545MHz, External signal input mode
Logic Block	4-1-1	Input voltage Low level for channel selection	ViL1	0	-	1.7	V	Pin 8: Low:67.25MHz, Open,High:61.25MHz
	4-1-2	Input voltage High level for channel selection	ViH1	2	-	Vcc	V	Pin 8
	4-2-1	Input voltage Low level for Carrier off mode selection	ViL2	0	-	1.7	V	Pin 6 Low,Open : Carrier off , Antenna SW Out Low
	4-2-2	Input voltage High level for Carrier off mode selection	ViH2	2	-	Vcc	V	Pin 6 High : Carrier on , Antenna SW Out High
	4-3-1	Input voltage Low level for reference signal mode selection	ViL3	0	-	1.2	V	Pin 1 Low : Internal oscillation mode with 4MHz X'tal
	4-3-2	Input voltage Middle level for reference signal mode selection	ViM3	1.8	2.5	3.2	V	Pin 1 Middle : 3.58MHz External signal input mode
	4-3-3	Input voltage High level for reference signal mode selection	ViH3	3.8	-	Vcc	V	Pin 1 Open,High : 4MHz External signal input mode
	4-4	Threshold voltage for power-on reset	VRESET	2.5	2.8	3.1	V	
	4-5-1	Input voltage Low level for Test mode selection	VII4	0	-	1.2	V	Pin 5 Low : Normal mode
	4-5-2	Input voltage High level for Test mode selection	ViH4	1.8	-	Vcc	V	Pin 5 High : Test mode

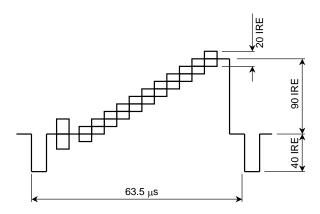
No.	Characteristics	Symbol	Min	Тур.	Max	Unit	Note
4-6	Output voltage Low level of Antenna SW driver	VOL	-	0	0.1	V	
4-7	Output voltage High level of Antenna SW driver	VOH	3.6	4	4.3	V	15mA load
5-1	Negative resistance of X'tal oscillator	RXO	-1	-	-	kΩ	
5-2	Input signal level of external reference signal	Vosc	50	10	-	mVp-p	External reference signal input Mode

## Input Waveforms

#### White signal

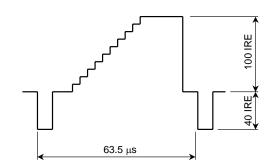


Staircase (sub-carrier 20 IRE) signal APL 50%

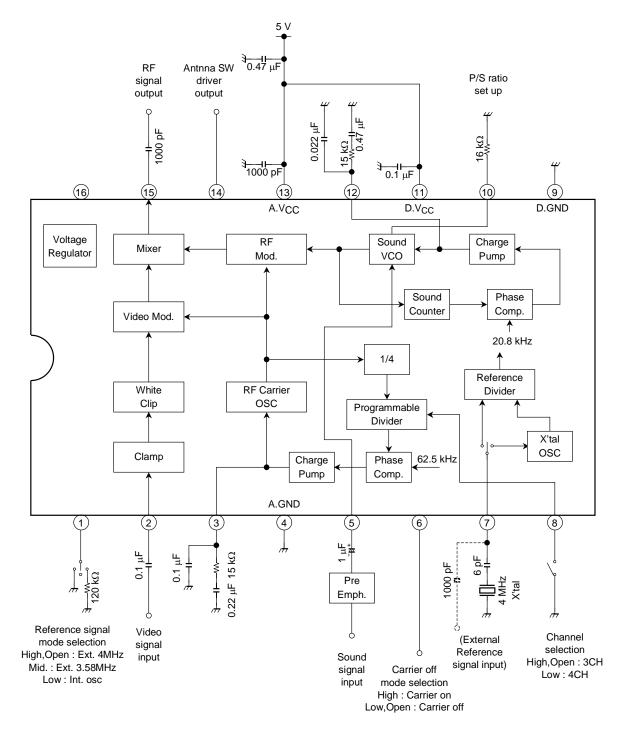


Input Waveforms may be simplified for explanatory purpose.

#### Staircase (B/W) signal APL50%



#### **Test and Application Circuit**



Components in the test circuits are only used to obtain and confirm the device characteristics. These components and circuits do not warrant to prevent the application equipment from malfunction or failure.

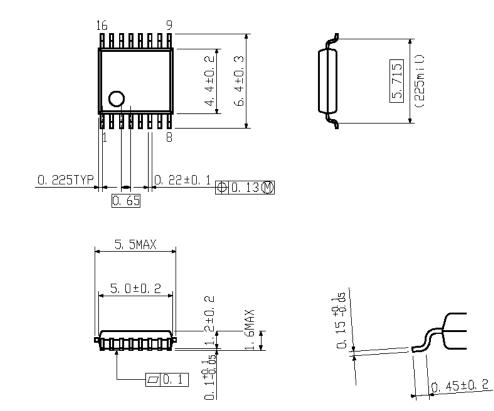
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#### **Handling Precautions**

- 1. Do not drive the device's power supply voltage High or Low until it is attached to an inspection board or similar test assembly. Attaching the device to, or removing it from the inspection board while it is powered on may damage the device or degrade its characteristics. The power supply voltage should not be applied suddenly. Any overshoot or chattering in the power supply may result in degradation of the IC's characteristics. A filter or similar protective component should be inserted on the power supply line.
- 2. If the voltage of a terminal 5(Sound signal input) becomes more than 1.2V, it will change to the test mode. Be careful of the influence of a noise etc.
- 3. The application circuits described in this document are merely intended as examples to enable the operation of the device to be evaluated. None of the peripheral circuit configurations shown or circuit constants specified are intended to be incorporated into application systems or used in designs for mass-produced equipment. Toshiba Corporation cannot assume responsibility for any damage arising from the use of any of these circuits. This is because the high-frequency characteristics of a device can vary according to a number of factors, including factors relating to the external components and the mounting pattern used. Therefore, the user must design external circuits according to the requirements of the specific application system, using this document as a reference only. The user must also test the application circuit's characteristics thoroughly. This document only guarantees device quality and characteristics as described herein; Toshiba Corporation cannot assume responsibility for any user's product design or application implementation.
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(Last updated: Dec. 2003)

### Package Dimensions



Weight: 0.07 g (typ.)

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